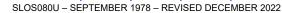






TL071, TL071A, TL071B, TL071H TL072, TL072A, TL072B, TL072H, TL072M TL074, TL074A, TL074B, TL074H, TL074M





TL07xx Low-Noise FET-Input Operational Amplifiers

1 Features

High slew rate: 20 V/µs (TL07xH, typ)

Low offset voltage: 1 mV (TL07xH, typ)

Low offset voltage drift: 2 µV/°C

Low power consumption: 940 µA/ch (TL07xH, typ)

Wide common-mode and differential voltage ranges

 Common-mode input voltage range includes V_{CC+}

Low input bias and offset currents

Low noise:

 $V_n = 18 \text{ nV}/\sqrt{\text{Hz}}$ (typ) at f = 1 kHz

Output short-circuit protection

Low total harmonic distortion: 0.003% (typ)

Wide supply voltage: ±2.25 V to ±20 V, 4.5 V to 40 V

2 Applications

- Solar energy: string and central inverter
- Motor drives: AC and servo drive control and power stage modules
- Single phase online UPS
- Three phase UPS
- Pro audio mixers
- Battery test equipment

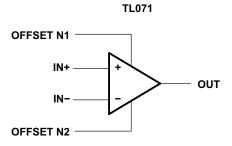
3 Description

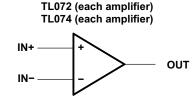
The TL07xH (TL071H, TL072H, and TL074H) family of devices are the next-generation versions of the industry-standard TL07x (TL071, TL072, and TL074) devices. These devices provide outstanding value for cost-sensitive applications, with features including low offset (1 mV, typical), high slew rate (20 V/µs), and common-mode input to the positive supply. High ESD (1.5 kV, HBM), integrated EMI and RF filters, and operation across the full -40°C to 125°C enable the TL07xH devices to be used in the most rugged and demanding applications.

Device Information

PART NUMBER(1)	PACKAGE	BODY SIZE (NOM)
	PDIP (8)	9.59 mm × 6.35 mm
	SC70 (5)	2.00 mm × 1.25 mm
TL071x	SO (8)	6.20 mm × 5.30 mm
	SOIC (8)	4.90 mm × 3.90 mm
	SOT-23 (5)	1.60 mm × 1.20 mm
	PDIP (8)	9.59 mm × 6.35 mm
	SO (8)	6.20 mm × 5.30 mm
TL072x	SOIC (8)	4.90 mm × 3.90 mm
	SOT-23 (8)	2.90 mm × 1.60 mm
	TSSOP (8)	4.40 mm × 3.00 mm
	CDIP (8)	9.59 mm × 6.67 mm
TL072M	CFP (10)	6.12 mm × 3.56 mm
	LCCC (20)	8.89 mm × 8.89 mm
	PDIP (14)	19.30 mm × 6.35 mm
	SO (14)	10.30 mm × 5.30 mm
TL074x	SOIC (14)	8.65 mm × 3.91 mm
TLU74X	SOT-23 (14)	4.20 mm × 2.00 mm
	SSOP (14)	6.20 mm × 5.30 mm
	TSSOP (14)	5.00 mm × 4.40 mm
	CDIP (14)	19.56 mm × 6.92 mm
TL074M	CFP (14)	9.21 mm × 6.29 mm
	LCCC (20)	8.89 mm × 8.89 mm

For all available packages, see the orderable addendum at the end of the data sheet.





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Logic Symbols



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C	hanges from Revision P (November 2020) to Revision Q (June 2021)	Page
•	Deleted VSSOP (8) package from the Device Information section	1
•	Added DBV, DCK, and D packages to TL071H in Pin Configuration and Functions section	4
•	Deleted DGK package from TL072x in Pin Configuration and Functions section	4
•	Deleted tables with duplicate information from the Specifications section	11
•	Added D, DCK, and DBV package thermal information in Thermal Information for Single Channel: TI section	
•	Added D, DDF, and PW package thermal information in Thermal Information for Dual Channel: TL072	2H
	section	
•	Added I _B and I _{OS} specification for single channel DCK and DBV package	
•	Added I _Q spec for TL071H Deleted Related Links section from the Device and Documentation Support section	
_	Deleted Nelated Links section from the Device and Documentation Support section	
С	hanges from Revision O (October 2020) to Revision P (November 2020)	Page
•	Added SOIC and TSSOP package thermal information in Thermal Information for Quad Channel: TL	074H
	section	13
•	Added Typical Characteristics:TL07xH section in Specifications section	19
С	hanges from Revision N (July 2017) to Revision O (October 2020)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	
•	Features of TL07xH added to the <i>Features</i> section	
•	Added link to applications in the <i>Applications</i> section	
•	Added TL07xH in the <i>Description</i> section	
•	Added TL07xH device in the <i>Device Information</i> section	
•	Added SOT-23 (14), VSSOP (8), SOT-23 (8), SC70 (5), and SOT-23 (5) packages to the Device Info	
	section	
•	Added TSSOP, VSSOP and DDF packages to TL072x in <i>Pin Configuration and Functions</i> section	
•	Added DYY package to TL074x in <i>Pin Configuration and Functions</i> section	
•	Removed Table of Graphs from the <i>Typical Characteistics</i> section	
•	Deleted reference to obsolete documentation in Layout Guidelines section	
•	Removed Related Documentation section	38
С	hanges from Revision M (February 2014) to Revision N (July 2017)	Page
•	Updated data sheet text to latest documentation and translation standards	
	Added TL072M and TL074M devices to data sheet	1
	Rewrote text in <i>Description</i> section	1
•	Changed TL07x 8-pin PDIP package to 8-pin CDIP package in <i>Device Information</i> table	
•	Deleted 20-pin LCCC package from <i>Device Information</i> table	
•	Added 2017 copyright statement to front page schematic	
•	Deleted TL071x FK (LCCC) pinout drawing and pinout table in Pin Configurations and Functions sec	
•	Updated pinout diagrams and pinout tables in Pin Configurations and Functions section	
•	Added Figure 6-59 to Typical Characteristics section	
•	Added second <i>Typical Application</i> section application curves	
•	Changed document references in Layout Guidelines section	
_	hongo from Davision I. (Echausau 2014) to Davision M. (Echausau 2014)	Desc
•	hanges from Revision L (February 2014) to Revision M (February 2014) Added Device Information table, Pin Configuration and Functions section, ESD Ratings table, Feature	Page e
	Description section, Device Functional Modes, Application and Implementation section, Power Suppl	
	Recommendations section, Layout section	-
	· •	

5 Pin Configuration and Functions



Figure 5-1. TL071H DBV Package 5-Pin SOT-23 (Top View)

Figure 5-2. TL071H DCK Package 5-Pin SC70 (Top View)

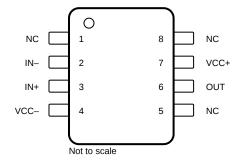


Figure 5-3. TL071H D Package 8-Pin SOIC (Top View)

Table 5-1. Pin Functions: TL071H

PIN				I/O	DESCRIPTION	
NAME	DBV	DCK	D	1/0	DESCRIPTION	
IN-	4	3	2	I	Inverting input	
IN+	3	1	3	I	Noninverting input	
NC	_	_	8	_	Do not connect	
NC	_	_	1	_	Do not connect	
NC	_	_	5	_	Do not connect	
OUT	1	4	6	0	Output	
VCC-	2	2	4	_	Power supply	
VCC+	5	5	7	_	Power supply	



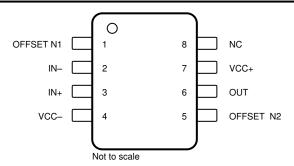


Figure 5-4. TL071x D, P, and PS Package 8-Pin SOIC, PDIP, and SO (Top View)

Table 5-2. Pin Functions: TL071x

P	IN	1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
IN-	2	1	Inverting input
IN+	3	1	Noninverting input
NC	8	_	Do not connect
OFFSET N1	1	_	Input offset adjustment
OFFSET N2	5	_	Input offset adjustment
OUT	6	0	Output
VCC-	4	_	Power supply
VCC+	7	_	Power supply



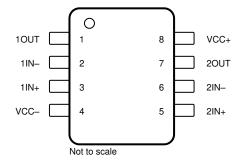


Figure 5-5. TL072x D, DDF, JG, P, PS, and PW Package 8-Pin SOIC, SOT-23 (8), CDIP, PDIP, SO, and TSSOP (Top View)

Table 5-3. Pin Functions: TL072x

	PIN	I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
1IN-	2	I	Inverting input
1IN+	3	I	Noninverting input
10UT	1	0	Output
2IN-	6	I	Inverting input
2IN+	5	I	Noninverting input
2OUT	7	0	Output
VCC-	4	_	Power supply
VCC+	8	_	Power supply



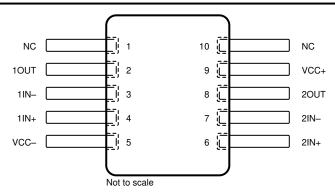


Figure 5-6. TL072x U Package 10-Pin CFP (Top View)

Table 5-4. Pin Functions: TL072x

	PIN	I/O	DESCRIPTION
NAME	NO.	- 1/0	DESCRIPTION
1IN-	3	I	Inverting input
1IN+	4	I	Noninverting input
10UT	2	0	Output
2IN-	7	I	Inverting input
2IN+	6	I	Noninverting input
2OUT	8	0	Output
NC	1, 10	_	Do not connect
VCC-	5	_	Power supply
VCC+	9	_	Power supply

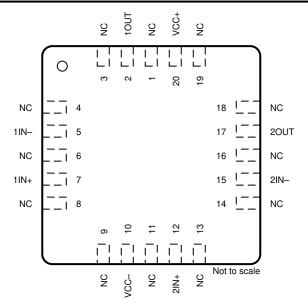


Figure 5-7. TL072 FK Package 20-Pin LCCC (Top View)

Table 5-5. Pin Functions: TL072x

	PIN	I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
1IN-	5	I	Inverting input
1IN+	7	I	Noninverting input
10UT	2	0	Output
2IN-	15	I	Inverting input
2IN+	12	I	Noninverting input
2OUT	17	0	Output
NC	1, 3, 4, 6, 8, 9, 11, 13, 14, 16, 18, 19	_	Do not connect
VCC-	10	_	Power supply
VCC+	20	_	Power supply



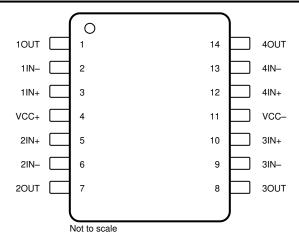


Figure 5-8. TL074x D, N, NS, PW, J, DYY, and W Package 14-Pin SOIC, PDIP, SO, TSSOP, CDIP, SOT-23 (14), and CFP (Top View)

Table 5-6. Pin Functions: TL074x

	PIN	- I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
1IN-	2	I	Inverting input
1IN+	3	I	Noninverting input
10UT	1	0	Output
2IN-	6	I	Inverting input
2IN+	5	I	Noninverting input
2OUT	7	0	Output
3IN-	9	1	Inverting input
3IN+	10	I	Noninverting input
3OUT	8	0	Output
4IN-	13	I	Inverting input
4IN+	12	1	Noninverting input
4OUT	14	0	Output
V _{CC} -	11	_	Power supply
V _{CC+}	4	_	Power supply

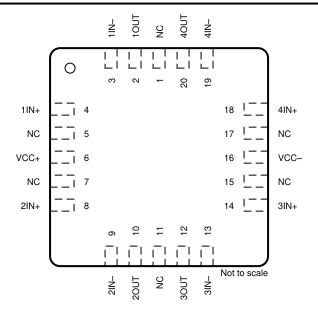


Figure 5-9. TL074 FK Package 20-Pin LCCC (Top View)

Table 5-7. Pin Functions: TL074x

Р	PIN		DESCRIPTION	
NAME	NO.	I/O		
1IN-	3	I	Inverting input	
1IN+	4	I	Noninverting input	
1OUT	2	0	Output	
2IN-	9	I	Inverting input	
2IN+	8	I	Noninverting input	
2OUT	10	0	Output	
3IN-	13	I	Inverting input	
3IN+	14	I	Noninverting input	
3OUT	12	0	Output	
4IN-	19	I	Inverting input	
4IN+	18	I	Noninverting input	
4OUT	20	0	Output	
NC	1, 5, 7, 11, 15, 17	_	Do not connect	
VCC-	16	_	Power supply	
VCC+	6	_	Power supply	



6 Specifications

6.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted) (1)

	· · · · · · · · · · · · · · · · · · ·		MIN	MAX	UNIT
Supply voltage, V _S = (V+) – (V–)		All NS and PS packages; All TL07xM devices	-0.3	36	V
Supply voltage, $v_S = (v_S)$	/+) - (V-)	All other devices	0	42	V
	Common mode veltage (3)	All NS and PS packages; All TL07xM devices	(V-) - 0.3	(V-) + 36	V
	Common-mode voltage (3)	All other devices	(V-) - 0.5	(V+) + 0.5	V
Signal input pins	Differential voltage (3)	All NS and PS packages; All TL07xM devices	(V-) - 0.3	(V–) + 36	V
		All other devices		V _S + 0.2	V
	Current (3)	All NS and PS packages; All TL07xM devices		50	mA
	Current	All other devices	-10	10	mA
Output short-circuit (2)			Continu	lous	
Operating ambient tem	perature, T _A		-55	150	°C
Junction temperature, T _J				150	°C
Case temperature for 60 seconds - FK package				260	°C
Lead temperature 1.8 mm (1/16 inch) from case for 10 seconds				300	°C
Storage temperature, T	stg		-65	150	°C

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Short-circuit to ground, one amplifier per package.
- (3) Input pins are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.
- (4) Differential voltage only limited by input voltage.

6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

			MIN	MAX	UNIT
Vs	Supply voltage, (V+) – (V–)	All NS and PS packages; All TL07xM devices ⁽¹⁾	10	30	V
		All other devices	4.5	40	V
VI	Input voltage range	All NS and PS packages; All TL07xM devices	(V-) + 2	(V+) + 0.1	V
		All other devices	(V-) + 4	(V+) + 0.1	V
		TL07xM	-55	125	°C
_	Charified town eveture	TL07xH	-40	125	°C
T _A	Specified temperature	TL07xI	-40	85	°C
		TL07xC	0	70	°C

(1) V+ and V- are not required to be of equal magnitude, provided that the total $V_S(V+-V-)$ is between 10 V and 30 V.

6.4 Thermal Information for Single Channel

			TL071xx					
THERMAL METRIC (1)		D (SOIC)	DCK (SC70)	DBV (SOT-23)	P (PDIP)	PS (SO)	UNIT	
		8 PINS	5 PINS	5 PINS	8 PINS	8 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	158.8	217.5	212.2	85	95	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	98.6	113.1	111.1	-	-	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	102.3	63.8	79.4	-	-	°C/W	
ΨЈТ	Junction-to-top characterization parameter	45.8	34.8	51.8	-	-	°C/W	
ΨЈВ	Junction-to-board characterization parameter	101.5	63.5	79.0	-	-	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

6.5 Thermal Information for Dual Channel

					TL0	72xx				
тн	THERMAL METRIC (1)		DDF (SOT-23)	FK (LCCC)	JG (CDIP)	P (PDIP)	PS (SO)	PW (TSSOP)	U (CFP)	UNIT
		8 PINS	8 PINS	20 PINS	8 PINS	8 PINS	8 PINS	8 PINS	10 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	147.8	181.5	-	-	85	95	200.3	169.8	°C/W
R ₀ JC(top)	Junction-to-case (top) thermal resistance	88.2	112.5	5.61	15.05	-	-	89.4	62.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	91.4	98.2	-	-	-	-	131.0	176.2	°C/W
Ψлт	Junction-to-top characterization parameter	36.8	17.2	_	_	_	_	22.2	48.4	°C/W
ΨЈВ	Junction-to-board characterization parameter	90.6	97.6	-	_	_	-	129.3	144.1	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	-	_	_	_	N/A	5.4	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.



6.6 Thermal Information for Quad Channel

				TL074xx						
	THERMAL METRIC (1)		DYY (SOT-23)	FK (TSSOP)	J (TSSOP)	N (TSSOP)	NS (TSSOP)	PW (TSSOP)	W (TSSOP)	UNIT
		14 PINS	14 PINS	20 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	114.2	153.2	-	-	80	76	-	128.8	°C/W
R _θ JC(top)	Junction-to-case (top) thermal resistance	70.3	88.7	5.61	14.5	-	-	14.5	56.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	70.2	65.4	-	-	-	-	-	127.6	°C/W
Ψлт	Junction-to-top characterization parameter	28.8	9.5	-	-	-	-	-	29	°C/W
ΨЈВ	Junction-to-board characterization parameter	69.8	65.0	-	-	-	-	-	106.1	°C/W
R _θ JC(bot)	Junction-to-case (bottom) thermal resistance	N/A	N/A	-	-	-	-	-	0.5	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

6.7 Electrical Characteristics: TL07xH

For $V_S = (V_{CC+}) - (V_{CC-}) = 4.5 \text{ V}$ to 40 V (±2.25 V to ±20 V) at $T_A = 25^{\circ}\text{C}$, $R_L = 10 \text{ k}\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{O\ UT} = V_S / 2$, unless otherwise noted.

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
OFFSET V	OLTAGE						
					±1	±4	
V _{OS}	Input offset voltage		T _A = -40°C to 125°C			±5	mV
dV _{OS} /dT	Input offset voltage drift		T _A = -40°C to 125°C		±2		μV/°C
	Input offset voltage versus	V _S = 5 V to 40 V, V _{CM} = V _S /				.40	
PSRR	power supply	2	$T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$		±1	±10	μV/V
	Channel separation	f = 0 Hz			10		μV/V
INPUT BIA	S CURRENT						
					±1	±120	pA
I _B	Input bias current		DCK and DBV packages		±1	±300	pА
			$T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ (1)			±5	nA
					±0.5	±120	pА
I _{OS}	Input offset current		DCK and DBV packages		±0.5	±250	pA
			$T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ (1)			±5	nA
NOISE							
					9.2		μV _{PP}
E _N	Input voltage noise	f = 0.1 Hz to 10 Hz			1.4		μV _{RMS}
		f = 1 kHz			37		1 KWO
e _N	Input voltage noise density	f = 10 kHz			21		nV/√ Hz
i _N	Input current noise	f = 1 kHz			80		fA/√ Hz
	LTAGE RANGE	1 1 KHZ					7,0,11,12
	Common-mode voltage						
V _{CM}	range			(V _{CC} -) + 1.5		(V _{CC+})	V
		V _S = 40 V, (V _{CC}) + 2.5 V <		100	105		dB
	Common-mode rejection	$V_{CM} < (V_{CC+}) - 1.5 \text{ V}$	T _A = -40°C to 125°C	95			dB
CMRR	ratio	V _S = 40 V, (V _{CC}) + 2.5 V <		90	105		dB
		V _{CM} < (V _{CC+})	T _A = -40°C to 125°C	80			dB
INPUT CAI	PACITANCE						
Z _{ID}	Differential				100 2		MΩ pF
Z _{ICM}	Common-mode				6 1		TΩ pF
OPEN-LOC					- 11		
		$V_S = 40 \text{ V}, V_{CM} = V_S / 2,$					
A _{OL}	Open-loop voltage gain	$(V_{CC-}) + 0.3 \text{ V} < V_O < (V_{CC+})$ - 0.3 V	$T_A = -40^{\circ}C \text{ to } 125^{\circ}C$	118	125		dB
A _{OL}	Open-loop voltage gain	$V_S = 40 \text{ V}, V_{CM} = V_S / 2, R_L = 2 \text{ k}\Omega, (V_{CC-}) + 1.2 \text{ V} < V_O < (V_{CC+}) - 1.2 \text{ V}$	T _A = -40°C to 125°C	115	120		dB
FREQUEN	CY RESPONSE						
GBW	Gain-bandwidth product				5.25		MHz
SR	Slew rate	V _S = 40 V, G = +1, C _L = 20 pF			20		V/µs
		To 0.1%, V _S = 40 V, V _{STEP} = 1	0 V , G = +1, CL = 20 pF		0.63		
	0 111 11	To 0.1%, V _S = 40 V, V _{STEP} = 2	V , G = +1, CL = 20 pF		0.56		
t _S	Settling time	To 0.01%, V _S = 40 V, V _{STEP} =		0.91		μs	
		To 0.01%, V _S = 40 V, V _{STEP} =			0.48		
	Phase margin	$G = +1$, $R_L = 10$ kΩ, $C_L = 20$ p			56		۰
	Overload recovery time	V _{IN} × gain > V _S			300		ns
THD+N	Total harmonic distortion + noise	$V_S = 40 \text{ V}, V_O = 6 \text{ V}_{RMS}, G = 40 \text{ V}$	+1, f = 1 kHz		0.00012		%
EMIRR	EMI rejection ratio	f = 1 GHz			53		dB
OUTPUT	wii rojeonom rano	1 0112					



6.7 Electrical Characteristics: TL07xH (continued)

For V_S = (V_{CC+}) – (V_{CC-}) = 4.5 V to 40 V (±2.25 V to ±20 V) at T_A = 25°C, R_L = 10 k Ω connected to V_S / 2, V_{CM} = V_S / 2, and $V_{O\ UT}$ = V_S / 2, unless otherwise noted.

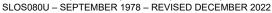
	PARAMETER	TEST (CONDITIONS	MIN	TYP	MAX	UNIT
		Danishina anii banadanaan	$V_S = 40 \text{ V}, R_L = 10 \text{ k}\Omega$		115	210	
	Voltage output swing from	Positive rail headroom	$V_S = 40 \text{ V}, R_L = 2 \text{ k}\Omega$		520	965	.,
	rail	$V_S = 40 \text{ V}, R_I = 1$	$V_S = 40 \text{ V}, R_L = 10 \text{ k}\Omega$		105	215	mV
		Negative rail headroom	$V_S = 40 \text{ V}, R_L = 2 \text{ k}\Omega$		500	1030	
I _{sc}	Short-circuit current				±26		mA
C _{LOAD}	Capacitive load drive				300		pF
Z _O	Open-loop output impedance	f = 1 MHz, I _O = 0 A			125		Ω
POWER	SUPPLY	1	,			'	
		I _O = 0 A			937.5	1125	
		I _O = 0 A, (TL071H)			960	1156	
IQ	Quiescent current per amplifier	I _O = 0 A				1130	μΑ
		I _O = 0 A, (TL072H)	T _A = -40°C to 125°C			1143	
	Ī	I _O = 0 A, (TL071H)				1160	i0
	Turn-On Time	At T _A = 25°C, V _S = 40 V, V _S	s ramp rate > 0.3 V/µs		60		μs

⁽¹⁾ ${\sf Max}\ {\sf I}_{\sf B}$ and ${\sf I}_{\sf os}$ data is specified based on characterization results.

6.8 Electrical Characteristics (DC): TL07xC, TL07xAC, TL07xBC, TL07xI, TL07xM

For $V_S = (V_{CC+}) - (V_{CC-}) = \pm 15 \text{ V}$ at $T_A = 25^{\circ}\text{C}$, unless otherwise noted

	PARAMETER		test conditions(1) (2)	MIN	TYP	MAX	UNIT	
			TL07xC			3	10		
			120720	T _A = Full range			13		
			TLOZVAC			3	6		
		V _O = 0 V	TL07xAC	T _A = Full range			7.5		
						2	3		
			TL07xBC	T _A = Full range			5		
/os	Input offset voltage	R _S = 50 Ω				3	6	mV	
			TL07xI	T _A = Full range			8		
				,		3	6		
			TL071M, TL072M	T _A = Full range			9		
				I A I am range		3	9		
			TL074M	T _A = Full range			15		
	Input offset voltage			1 _A - 1 ull range		,	13		
dV _{OS} /dT	drift	$V_{O} = 0 \text{ V}, R_{S} = 50 \Omega$	T _A = Full range			±18		μV/°(
						5	100	pA	
			TL07xC	T _A = Full range			10	nA	
			TL07xAC, TL07xBC,	7		5	100	pA	
los	Input offset current	V _O = 0 V	TL07xAC, TL07xBC,	T _A = Full range			2	nA	
				TA - Full fully		5	100	pА	
			TL07xM	T _A = Full range			20	nA	
				TA - Full fallige					
			TL07xC, TL07xAC, TL07xBC, TL07xI	T 5 "		65	200	pA	
В			TEOTADO, TEOTAI	T _A = Full range			7	nA	
	Input bias current	V _O = 0 V	TL071M, TL072M			65	200	pA	
				T _A = Full range			50	nA	
			TL074M			65	200	pA	
				T _A = Full range			20	nA	
/ _{CM}	Common-mode				±11	–12 to 15		V	
	voltage range	D = 40 k0			.40	.40.5			
1014	Maximum peak output	$R_L = 10 \text{ k}\Omega$			±12	±13.5		.,	
/OM	voltage swing	R _L ≥ 10 kΩ	T _A = Full range	Full range				V	
		R _L ≥ 2 kΩ			±10				
			TL07xC		25	200			
				T _A = Full range	15				
A _{OL}	Open-loop voltage	V _O = 0 V	TL07xAC, TL07xBC,		50	200		V/m\	
OL	gain	5	TL07xI	T _A = Full range	25			•,,,,,	
			TL07xM		35	200			
			I LUTAIVI	T _A = Full range	15				
	Gain-bandwidth	All NS and PS package	es; All TL07xM devices			3		MHz	
GBW	product	All other devices				5.25		IVIHZ	
R _{ID}	Common-mode input					1		ΤΩ	
ND	resistance							1 3 2	
	Commercial	$V_{IC} = V_{ICR(min)}$	TL07xC		70	100			
CMRR	Common-mode rejection ratio	$V_O = 0 V$	TL07xAC, TL07xBC, TI	_07xl	75	100]	dB	
	,	$R_S = 50 \Omega$	TL07xM		80	86			
		V _S = ±9 V to ± 18 V	TL07xC		70	100			
PSRR	Input offset voltage	$V_0 = 0 V$	TL07xAC, TL07xBC, TI	_07xI	80	100		dB	
	versus power supply	$R_S = 50 \Omega$	TL07xM		80	86			
	Quiescent current per								
Q	amplifier	V _O = 0 V; no load				1.4	2.5	mA	





6.8 Electrical Characteristics (DC): TL07xC, TL07xAC, TL07xBC, TL07xI, TL07xM (continued)

For $V_S = (V_{CC+}) - (V_{CC-}) = \pm 15 \text{ V}$ at $T_A = 25^{\circ}\text{C}$, unless otherwise noted

PARAMETER	TEST CONDITIONS ⁽¹⁾ (2)	MIN TYP MAX		UNIT	
Channel separation	f = 0 Hz		1		μV/V

¹⁾ All characteristics are measured under open-loop conditions with zero common-mode voltage, unless otherwise specified.

⁽²⁾ Full range is $T_A = 0^{\circ}$ C to 70°C for the TL07xC, TL07xAC, and TL07xBC; $T_A = -40^{\circ}$ C to 85°C for the TL07xI; and $T_A = -55^{\circ}$ C to 125°C for the TL07xM.

6.9 Electrical Characteristics (AC): TL07xC, TL07xAC, TL07xBC, TL07xI, TL07xM

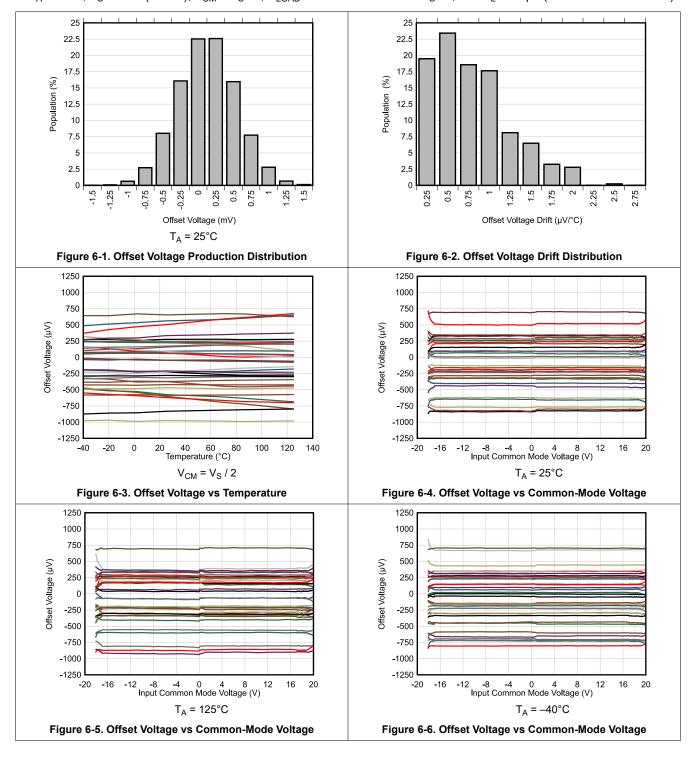
For $V_S = (V_{CC+}) - (V_{CC-}) = \pm 15 \text{ V}$ at $T_A = 25^{\circ}\text{C}$, unless otherwise noted.

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
		V _I = 10 V, C _L = 100 pF, R _L =	TL07xM	5	20		V/µs
SR	Slew rate	V ₁ = 10 V, C _L = 100 pF, R _L = 2 kΩ	TL07xC, TL07xAC, TL07xBC, TL07xI	8	20		V/µs
	Cattling time	$V_1 = 20 \text{ V}, C_1 = 100 \text{ pF}, R_1 = 2$	140		0.1		μs
t _S	Settling time	V ₁ = 20 V, C _L = 100 pr, R _L = 2	. K22		20%		
		All PS and NS packages; All TL07xM devices	R _S = 20 Ω, f = 1 kHz		18		nV/√ Hz
e _N	Input voltage noise density	All other devices	f = 1 kHz		37		nV/√ Hz
		All other devices	f = 10 kHz		21		nv/√HZ
E _N	Input voltage noise	All PS and NS packages; All TL07xM devices	R _S = 20 Ω, f = 10 Hz to 10 kHz		4		μV_{RMS}
		All other devices	f = 0.1 Hz to 10 Hz		1.4		μV _{RMS}
i _N	Input current noise	R _S = 20 Ω, f = 1 kHz		,	10		fA/√ Hz
	Phase margin	TL07xC, TL07xAC, TL07xBC, TL07xI	$G = +1$, $R_L = 10$ kΩ, $C_L = 20$ pF		56		٥
	Overload recovery time	V _{IN} × gain > V _S			300		ns
THD+N	Total harmonic distortion +	All PS and NS packages; All TL07xM devices	$V_O = 6 V_{RMS}, R_L \ge 2 kΩ, f = 1 kHz, G = +1, R_S \le 1 kΩ$		0.003		%
I HD+N	noise	All other devices	V _S = 40 V, V _O = 6 V _{RMS} , G = +1, f = 1 kHz		0.00012		%
EMIRR	EMI rejection ratio	TL07xC, TL07xAC, TL07xBC, TL07xI	f = 1 GHz		53		dB
Z _O	Open-loop output impedance	TL07xC, TL07xAC, TL07xBC, TL07xI	f = 1 MHz, I _O = 0 A		125		Ω

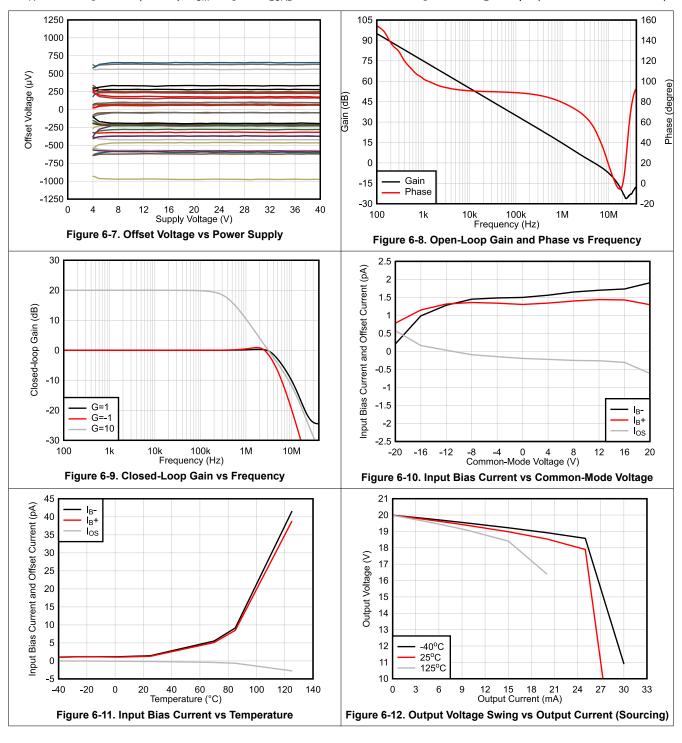


6.10 Typical Characteristics: TL07xH

at T_A = 25°C, V_S = 40 V (±20 V), V_{CM} = V_S / 2, R_{LOAD} = 10 k Ω connected to V_S / 2, and C_L = 20 pF (unless otherwise noted)

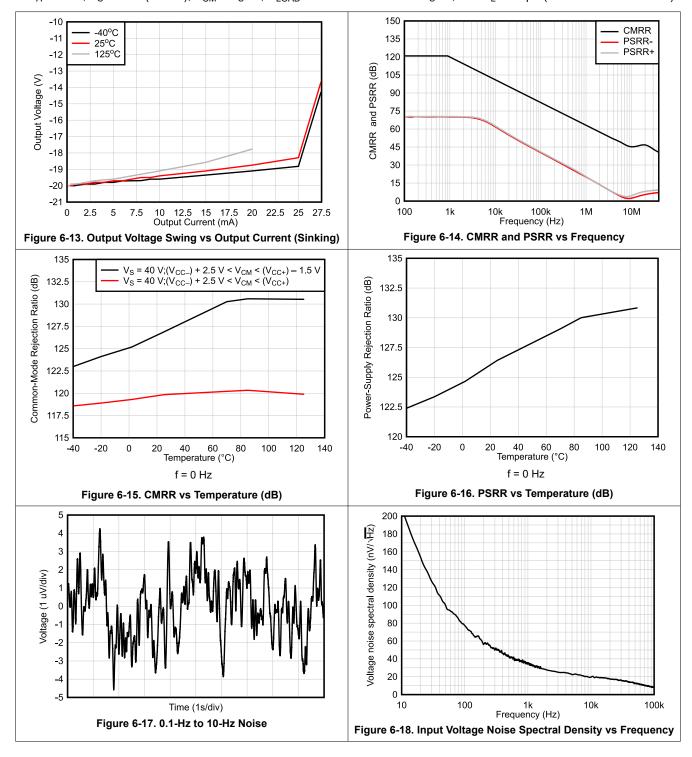


at T_A = 25°C, V_S = 40 V (±20 V), V_{CM} = V_S / 2, R_{LOAD} = 10 k Ω connected to V_S / 2, and C_L = 20 pF (unless otherwise noted)

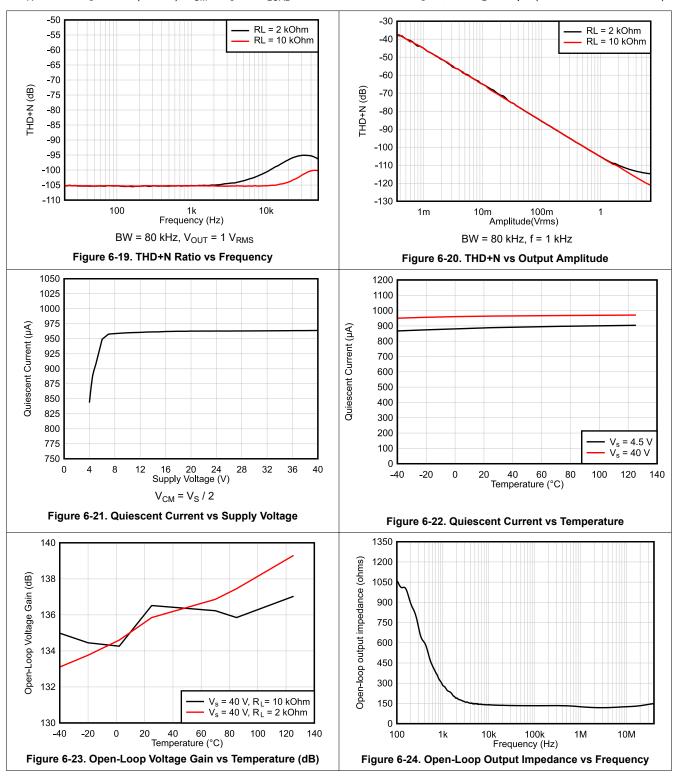




at $T_A = 25$ °C, $V_S = 40$ V (± 20 V), $V_{CM} = V_S / 2$, $R_{LOAD} = 10$ k Ω connected to $V_S / 2$, and $C_L = 20$ pF (unless otherwise noted)

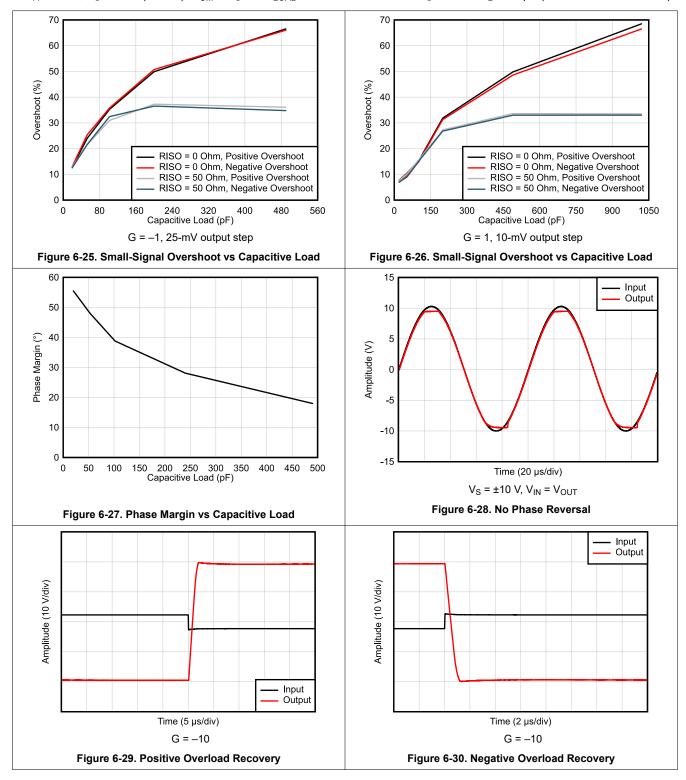


at $T_A = 25$ °C, $V_S = 40$ V (± 20 V), $V_{CM} = V_S$ / 2, $R_{LOAD} = 10$ k Ω connected to V_S / 2, and $C_L = 20$ pF (unless otherwise noted)

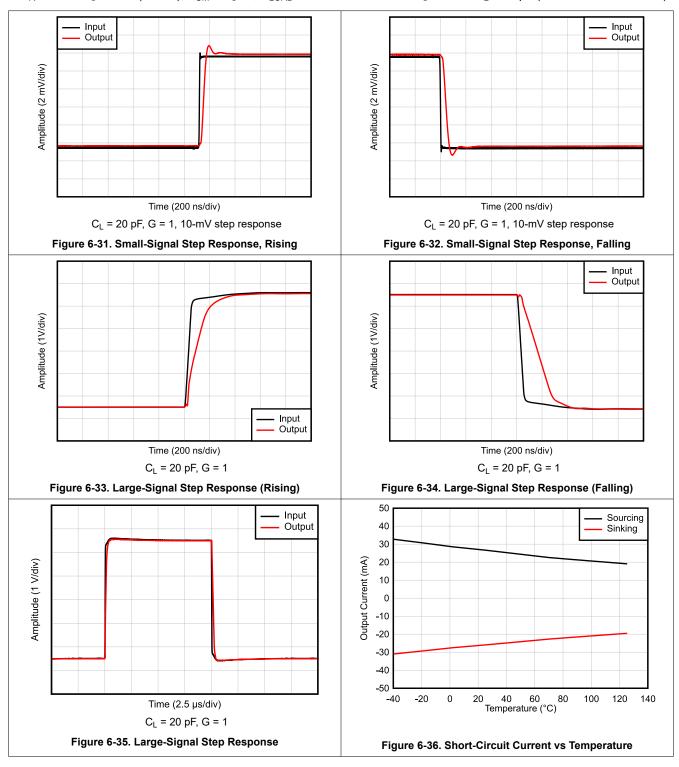




at T_A = 25°C, V_S = 40 V (±20 V), V_{CM} = V_S / 2, R_{LOAD} = 10 k Ω connected to V_S / 2, and C_L = 20 pF (unless otherwise noted)

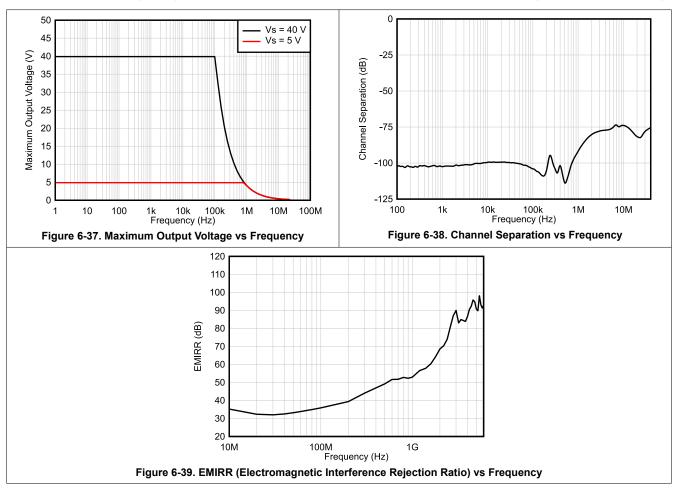


at $T_A = 25$ °C, $V_S = 40$ V (± 20 V), $V_{CM} = V_S / 2$, $R_{LOAD} = 10$ k Ω connected to $V_S / 2$, and $C_L = 20$ pF (unless otherwise noted)

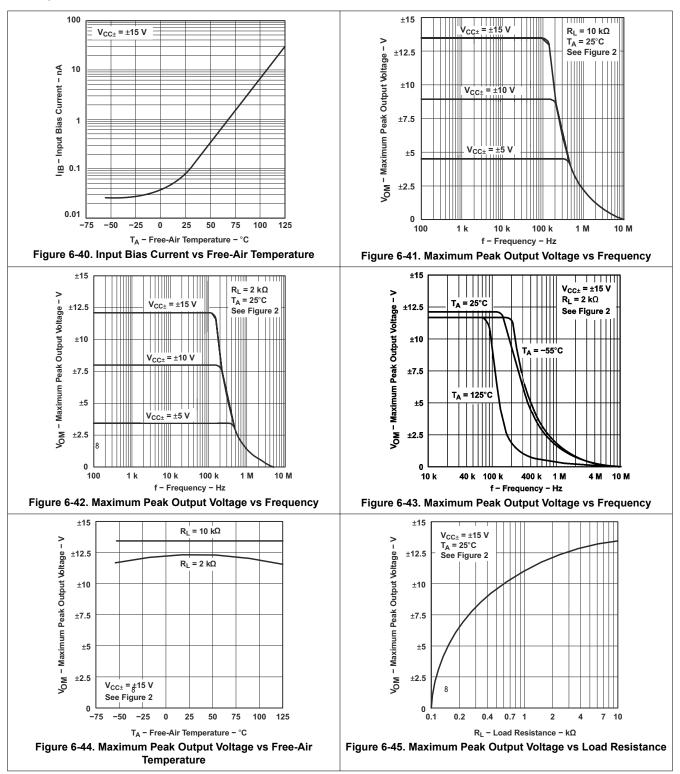




at $T_A = 25$ °C, $V_S = 40$ V (± 20 V), $V_{CM} = V_S / 2$, $R_{LOAD} = 10$ k Ω connected to $V_S / 2$, and $C_L = 20$ pF (unless otherwise noted)

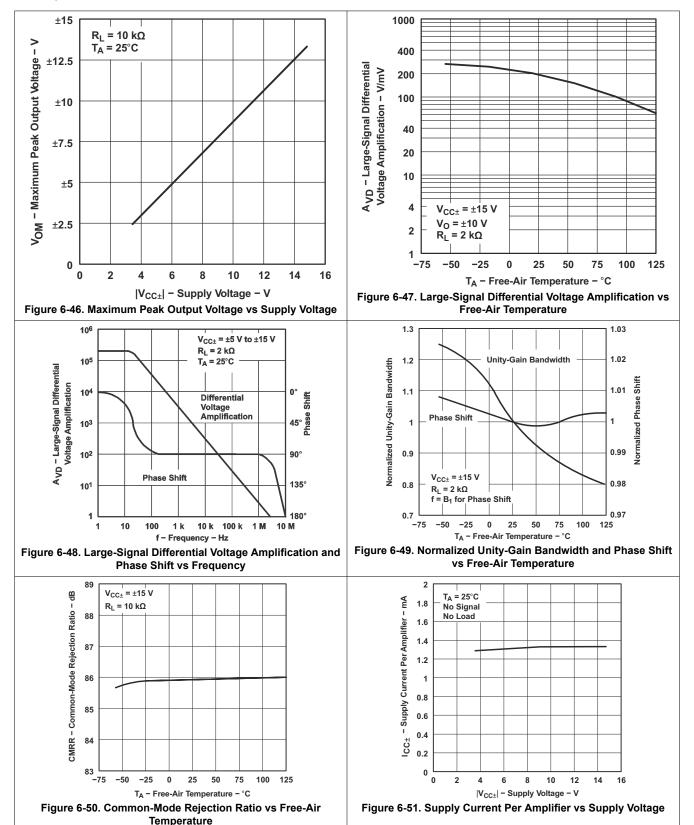


6.11 Typical Characteristics: All Devices Except TL07xH





6.11 Typical Characteristics: All Devices Except TL07xH (continued)



V_{CC±} =±15 V

No Signal No Load

TL074

75

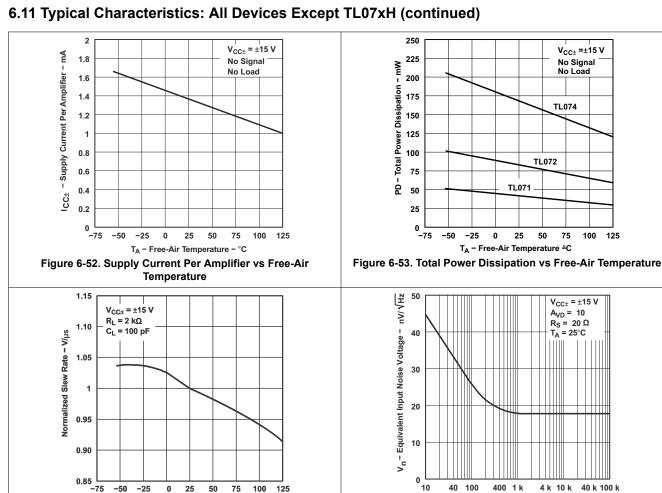
TL072

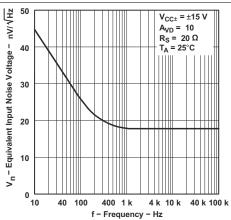
TL071

T_A - Free-Air Temperature °C

0 25

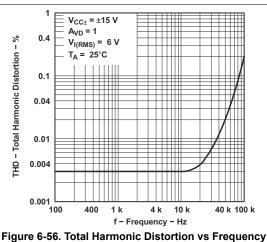
6.11 Typical Characteristics: All Devices Except TL07xH (continued)

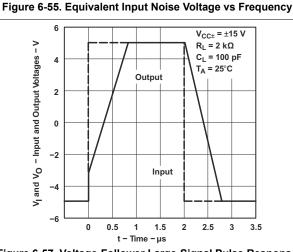






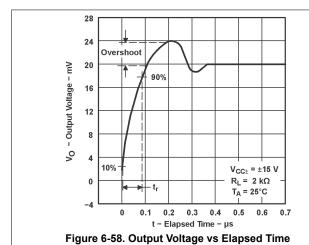
T_A - Free-Air Temperature - °C

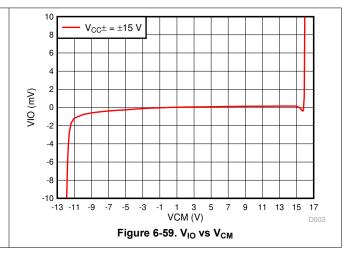






6.11 Typical Characteristics: All Devices Except TL07xH (continued)





7 Parameter Measurement Information

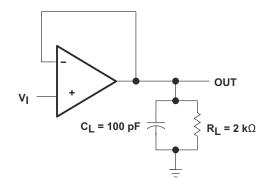


Figure 7-1. Unity-Gain Amplifier

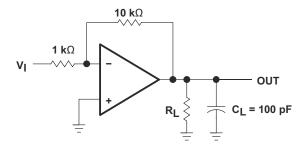


Figure 7-2. Gain-of-10 Inverting Amplifier

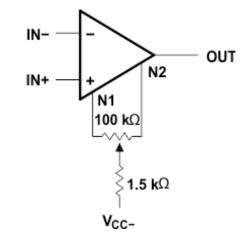


Figure 7-3. Input Offset-Voltage Null Circuit



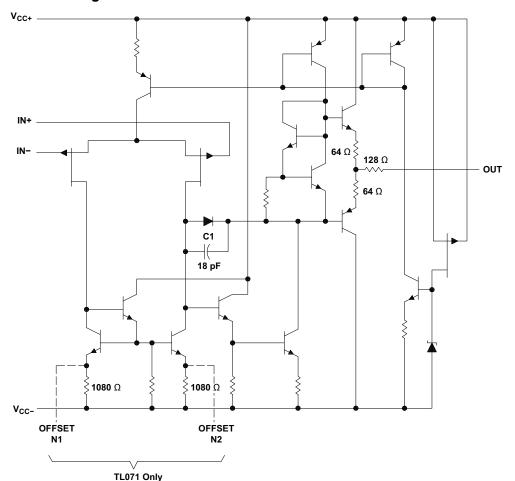
8 Detailed Description

8.1 Overview

The TL07xH (TL071H, TL072H, and TL074H) family of devices are the next-generation versions of the industry-standard TL07x (TL071, TL072, and TL074) devices. These devices provide outstanding value for cost-sensitive applications, with features including low offset (1 mV, typ), high slew rate (25 V/µs, typ), and common-mode input to the positive supply. High ESD (1.5 kV, HBM), integrated EMI and RF filters, and operation across the full –40°C to 125°C enable the TL07xH devices to be used in the most rugged and demanding applications.

The C-suffix devices are characterized for operation from 0° C to 70° C. The I-suffix devices are characterized for operation from -40° C to $+85^{\circ}$ C. The M-suffix devices are characterized for operation over the full military temperature range of -55° C to $+125^{\circ}$ C.

8.2 Functional Block Diagram



All component values shown are nominal.

COMPONENT COUNT [†]							
COMPONENT TYPE	TL071	TL072	TL074				
Resistors	11	22	44				
Transistors	14	28	56				
JFET	2	4	6				
Diodes	1	2	4				
Capacitors	1	2	4				
epi-FET	1	2	4				

[†] Includes bias and trim circuitry



8.3 Feature Description

The TL07xH family of devices improve many specifications as compared to the industry-standard TL07x family. Several comparisons of key specifications between these families are included below to show the advantages of the TL07xH family.

8.3.1 Total Harmonic Distortion

Harmonic distortions to an audio signal are created by electronic components in a circuit. Total harmonic distortion (THD) is a measure of harmonic distortions accumulated by a signal in an audio system. These devices have a very low THD of 0.003% meaning that the TL07x device adds little harmonic distortion when used in audio signal applications.

8.3.2 Slew Rate

The slew rate is the rate at which an operational amplifier can change the output when there is a change on the input. These devices have a $13-V/\mu s$ slew rate.

8.4 Device Functional Modes

These devices are powered on when the supply is connected. These devices can be operated as a single-supply operational amplifier or dual-supply amplifier depending on the application.



9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

A typical application for an operational amplifier is an inverting amplifier. This amplifier takes a positive voltage on the input, and makes the voltage a negative voltage. In the same manner, the amplifier makes negative voltages positive.

9.2 Typical Application

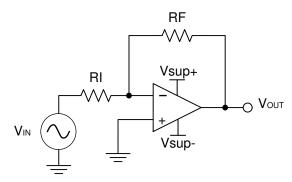


Figure 9-1. Inverting Amplifier

9.2.1 Design Requirements

The supply voltage must be selected so the supply voltage is larger than the input voltage range and output range. For instance, this application scales a signal of ± 0.5 V to ± 1.8 V. Setting the supply at ± 12 V is sufficient to accommodate this application.

9.2.2 Detailed Design Procedure

$$V_o = (V_i + V_{io})^* \left(1 + \frac{1M\Omega}{1k\Omega}\right)$$
 (1)

Determine the gain required by the inverting amplifier:

$$A_{V} = \frac{VOUT}{VIN}$$
 (2)

$$A_V = \frac{1.8}{-0.5} = -3.6 \tag{3}$$

Once the desired gain is determined, select a value for RI or RF. Selecting a value in the kilohm range is desirable because the amplifier circuit uses currents in the milliamp range. This ensures the part does not draw too much current. This example uses 10 k Ω for RI which means 36 k Ω is used for RF. This is determined by Equation 4.

$$A_{V} = -\frac{RF}{RI} \tag{4}$$

9.2.3 Application Curve

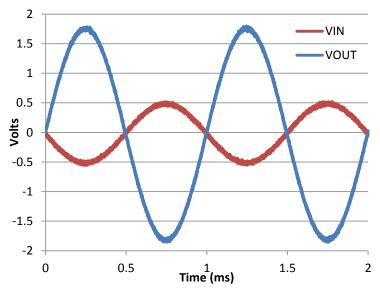


Figure 9-2. Input and Output Voltages of the Inverting Amplifier

9.3 Unity Gain Buffer

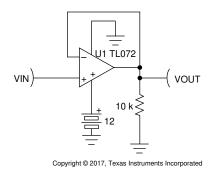


Figure 9-3. Single-Supply Unity Gain Amplifier

9.3.1 Design Requirements

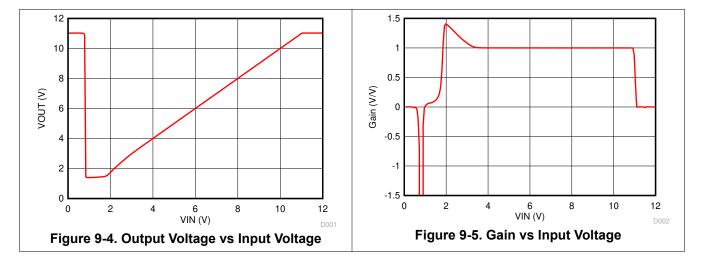
- V_{CC} must be within valid range per Recommended Operating Conditions. This example uses a value of 12 V for V_{CC}.
- Input voltage must be within the recommended common-mode range, as shown in Recommended Operating Conditions. The valid common-mode range is 4 V to 12 V (V_{CC} + 4 V to V_{CC+}).
- Output is limited by output range, which is typically 1.5 V to 10.5 V, or V_{CC} + 1.5 V to V_{CC+} 1.5 V.

9.3.2 Detailed Design Procedure

- Avoid input voltage values below 1 V to prevent phase reversal where output goes high.
- Avoid input values below 4 V to prevent degraded V_{IO} that results in an apparent gain greater than 1. This
 may cause instability in some second-order filter designs.



9.3.3 Application Curves



9.4 System Examples

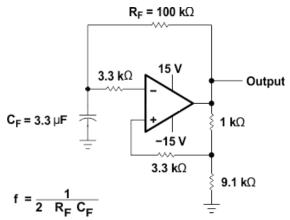


Figure 9-6. 0.5-Hz Square-Wave Oscillator

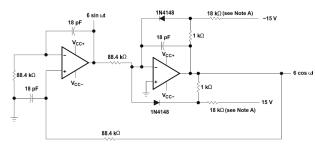


Figure 9-8. 100-kHz Quadrature Oscillator

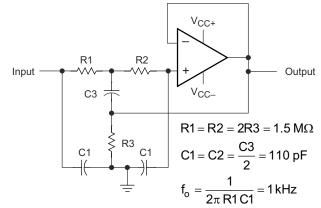


Figure 9-7. High-Q Notch Filter

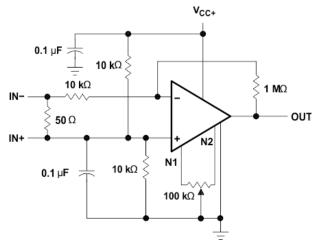


Figure 9-9. AC Amplifier



9.5 Power Supply Recommendations

CAUTION

Supply voltages larger than 36 V for a single-supply or outside the range of ±18 V for a dual-supply can permanently damage the device (see Section 6.1).

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see Section 9.6.

9.6 Layout

9.6.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the
 operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low impedance
 power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as
 close to the device as possible. A single bypass capacitor from V_{CC+} to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes.
 A ground plane helps distribute heat and reduces EMI noise pickup. Take care to physically separate digital
 and analog grounds, paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in Section 9.6.2.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.



9.6.2 Layout Example

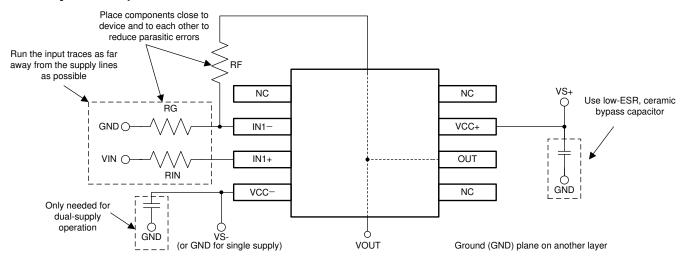


Figure 9-10. Operational Amplifier Board Layout for Noninverting Configuration

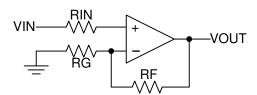


Figure 9-11. Operational Amplifier Schematic for Noninverting Configuration



10 Device and Documentation Support

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.





1-Apr-2023 www.ti.com

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
81023052A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	81023052A TL072MFKB	Samples
8102305HA	ACTIVE	CFP	U	10	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8102305HA TL072M	Samples
8102305PA	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8102305PA TL072M	Sample
81023062A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	81023062A TL074MFKB	Sample
8102306CA	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8102306CA TL074MJB	Sample
8102306DA	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8102306DA TL074MWB	Sample
JM38510/11905BPA	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510 /11905BPA	Sample
M38510/11905BPA	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510 /11905BPA	Sample
TL071ACD	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	071AC	
TL071ACDG4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	071AC	
TL071ACDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	071AC	Sampl
TL071ACP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL071ACP	Sample
TL071BCD	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	071BC	
TL071BCDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	071BC	Sampl
TL071BCP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL071BCP	Sampl
TL071CD	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL071C	
TL071CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL071C	Sampl
TL071CDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL071C	Sampl
TL071CDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL071C	Sampl
TL071CP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL071CP	Sampl





Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
TL071CPE4	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL071CP	Samples
TL071CPSR	ACTIVE	SO	PS	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T071	Samples
TL071HIDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T71V	Samples
TL071HIDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	110	Samples
TL071HIDR	ACTIVE	SOIC	D	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL071D	Samples
TL071ID	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL071I	
TL071IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL071I	Samples
TL071IDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL071I	Samples
TL071IP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	TL071IP	Samples
TL072ACD	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072AC	
TL072ACDE4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072AC	
TL072ACDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072AC	Samples
TL072ACDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072AC	Samples
TL072ACDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072AC	Sample
TL072ACP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL072ACP	Sample
TL072ACPE4	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL072ACP	Sample
TL072BCD	NRND	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072BC	
TL072BCDE4	NRND	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072BC	
TL072BCDG4	NRND	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072BC	
TL072BCDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	072BC	Sample
TL072BCP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL072BCP	Sample
TL072CD	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL072C	
TL072CDE4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL072C	
TL072CDG4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL072C	





Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TL072CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL072C	Samples
TL072CDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL072C	Samples
TL072CDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL072C	Samples
TL072CP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL072CP	Samples
TL072CPE4	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL072CP	Samples
TL072CPS	ACTIVE	SO	PS	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T072	Samples
TL072CPSR	ACTIVE	SO	PS	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T072	Samples
TL072CPSRG4	ACTIVE	SO	PS	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T072	Samples
TL072CPWR	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T072	Samples
TL072CPWRE4	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T072	Samples
TL072CPWRG4	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T072	Samples
TL072HIDDFR	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	O72F	Samples
TL072HIDR	ACTIVE	SOIC	D	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL072D	Samples
TL072HIPWR	ACTIVE	TSSOP	PW	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	072HPW	Samples
TL072ID	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL072I	
TL072IDE4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL072I	
TL072IDG4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL072I	
TL072IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL072I	Samples
TL072IDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL072I	Samples
TL072IDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL072I	Samples
TL072IP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	TL072IP	Samples
TL072IPE4	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	TL072IP	Samples





Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TL072MFKB	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	81023052A TL072MFKB	Samples
TL072MJG	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	TL072MJG	Samples
TL072MJGB	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8102305PA TL072M	Samples
TL072MUB	ACTIVE	CFP	U	10	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8102305HA TL072M	Samples
TL074ACD	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074AC	
TL074ACDE4	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074AC	
TL074ACDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074AC	Samples
TL074ACDRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074AC	Samples
TL074ACN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL074ACN	Samples
TL074ACNE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL074ACN	Samples
TL074ACNSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074A	Samples
TL074BCD	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074BC	
TL074BCDE4	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074BC	
TL074BCDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074BC	Samples
TL074BCDRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074BC	Samples
TL074BCDRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074BC	Samples
TL074BCN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL074BCN	Samples
TL074BCNE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL074BCN	Samples
TL074CD	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074C	
TL074CDBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T074	Samples
TL074CDG4	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074C	
TL074CDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	0 to 70	TL074C	Samples





Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TL074CDRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074C	Samples
TL074CN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL074CN	Samples
TL074CNE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL074CN	Samples
TL074CNSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL074	Samples
TL074CPW	LIFEBUY	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T074	
TL074CPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T074	Samples
TL074CPWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T074	Samples
TL074CPWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T074	Samples
TL074HIDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL074HID	Samples
TL074HIDYYR	ACTIVE	SOT-23-THIN	DYY	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T074HDYY	Samples
TL074HIPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL074PW	Samples
TL074ID	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL074I	
TL074IDE4	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL074I	
TL074IDG4	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL074I	
TL074IDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL074I	Samples
TL074IDRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL074I	Samples
TL074IDRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL074I	Samples
TL074IN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	TL074IN	Samples
TL074MFK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	TL074MFK	Samples
TL074MFKB	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	81023062A TL074MFKB	Samples
TL074MJ	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	TL074MJ	Samples



PACKAGE OPTION ADDENDUM

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TL074MJB	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8102306CA TL074MJB	Samples
TL074MWB	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8102306DA TL074MWB	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF TL072, TL072M, TL074, TL074M:

• Enhanced Product: TL072-EP, TL072-EP, TL074-EP, TL074-EP

Military : TL072M, TL074M

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

• Military - QML certified for Military and Defense Applications



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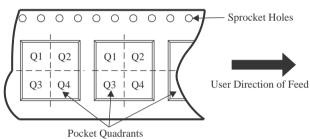
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL071ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL071BCDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL071CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL071CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL071CPSR	so	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
TL071HIDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL071HIDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TL071HIDR	SOIC	D	8	3000	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL071IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL072ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL072BCDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL072CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL072CPSR	so	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
TL072CPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TL072HIDDFR	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



PACKAGE MATERIALS INFORMATION

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL072HIDR	SOIC	D	8	3000	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL072HIPWR	TSSOP	PW	8	3000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TL072IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL074ACDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL074ACNSR	so	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
TL074BCDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL074CDBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
TL074CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL074CDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL074CNSR	so	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
TL074CPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL074HIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL074HIDYYR	SOT-23- THIN	DYY	14	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
TL074HIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL074IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL071ACDR	SOIC	D	8	2500	340.5	336.1	25.0
TL071BCDR	SOIC	D	8	2500	340.5	336.1	25.0
TL071CDR	SOIC	D	8	2500	356.0	356.0	35.0
TL071CDR	SOIC	D	8	2500	340.5	336.1	25.0
TL071CPSR	SO	PS	8	2000	356.0	356.0	35.0
TL071HIDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TL071HIDCKR	SC70	DCK	5	3000	190.0	190.0	30.0
TL071HIDR	SOIC	D	8	3000	356.0	356.0	35.0
TL071IDR	SOIC	D	8	2500	340.5	336.1	25.0
TL072ACDR	SOIC	D	8	2500	340.5	336.1	25.0
TL072BCDR	SOIC	D	8	2500	340.5	336.1	25.0
TL072CDR	SOIC	D	8	2500	340.5	336.1	25.0
TL072CPSR	SO	PS	8	2000	356.0	356.0	35.0
TL072CPWR	TSSOP	PW	8	2000	356.0	356.0	35.0
TL072HIDDFR	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
TL072HIDR	SOIC	D	8	3000	356.0	356.0	35.0
TL072HIPWR	TSSOP	PW	8	3000	356.0	356.0	35.0
TL072IDR	SOIC	D	8	2500	340.5	336.1	25.0



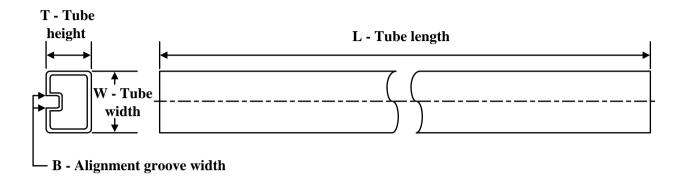
PACKAGE MATERIALS INFORMATION

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL074ACDR	SOIC	D	14	2500	340.5	336.1	32.0
TL074ACNSR	so	NS	14	2000	356.0	356.0	35.0
TL074BCDR	SOIC	D	14	2500	340.5	336.1	32.0
TL074CDBR	SSOP	DB	14	2000	356.0	356.0	35.0
TL074CDR	SOIC	D	14	2500	340.5	336.1	32.0
TL074CDRG4	SOIC	D	14	2500	340.5	336.1	32.0
TL074CNSR	so	NS	14	2000	356.0	356.0	35.0
TL074CPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
TL074HIDR	SOIC	D	14	2500	356.0	356.0	35.0
TL074HIDYYR	SOT-23-THIN	DYY	14	3000	336.6	336.6	31.8
TL074HIPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
TL074IDR	SOIC	D	14	2500	340.5	336.1	32.0



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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
81023052A	FK	LCCC	20	1	506.98	12.06	2030	NA
8102305HA	U	CFP	10	1	506.98	26.16	6220	NA
81023062A	FK	LCCC	20	1	506.98	12.06	2030	NA
8102306DA	W	CFP	14	1	506.98	26.16	6220	NA
TL071ACD	D	SOIC	8	75	507	8	3940	4.32
TL071ACDG4	D	SOIC	8	75	507	8	3940	4.32
TL071ACP	Р	PDIP	8	50	506	13.97	11230	4.32
TL071BCD	D	SOIC	8	75	507	8	3940	4.32
TL071BCP	Р	PDIP	8	50	506	13.97	11230	4.32
TL071CD	D	SOIC	8	75	506.6	8	3940	4.32
TL071CD	D	SOIC	8	75	507	8	3940	4.32
TL071CP	Р	PDIP	8	50	506	13.97	11230	4.32
TL071CPE4	Р	PDIP	8	50	506	13.97	11230	4.32
TL071ID	D	SOIC	8	75	507	8	3940	4.32
TL071IP	Р	PDIP	8	50	506	13.97	11230	4.32
TL072ACD	D	SOIC	8	75	507	8	3940	4.32
TL072ACDE4	D	SOIC	8	75	507	8	3940	4.32
TL072ACP	Р	PDIP	8	50	506	13.97	11230	4.32
TL072ACPE4	Р	PDIP	8	50	506	13.97	11230	4.32
TL072BCD	D	SOIC	8	75	507	8	3940	4.32
TL072BCDE4	D	SOIC	8	75	507	8	3940	4.32
TL072BCDG4	D	SOIC	8	75	507	8	3940	4.32
TL072BCP	Р	PDIP	8	50	506	13.97	11230	4.32
TL072CD	D	SOIC	8	75	506.6	8	3940	4.32
TL072CD	D	SOIC	8	75	507	8	3940	4.32
TL072CDE4	D	SOIC	8	75	506.6	8	3940	4.32
TL072CDE4	D	SOIC	8	75	507	8	3940	4.32
TL072CDG4	D	SOIC	8	75	506.6	8	3940	4.32
TL072CDG4	D	SOIC	8	75	507	8	3940	4.32



PACKAGE MATERIALS INFORMATION

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TL072CP	Р	PDIP	8	50	506	13.97	11230	4.32
TL072CPE4	Р	PDIP	8	50	506	13.97	11230	4.32
TL072CPS	PS	SOP	8	80	530	10.5	4000	4.1
TL072ID	D	SOIC	8	75	507	8	3940	4.32
TL072ID	D	SOIC	8	75	506.6	8	3940	4.32
TL072IDE4	D	SOIC	8	75	506.6	8	3940	4.32
TL072IDE4	D	SOIC	8	75	507	8	3940	4.32
TL072IDG4	D	SOIC	8	75	506.6	8	3940	4.32
TL072IDG4	D	SOIC	8	75	507	8	3940	4.32
TL072IP	Р	PDIP	8	50	506	13.97	11230	4.32
TL072IPE4	Р	PDIP	8	50	506	13.97	11230	4.32
TL072MFKB	FK	LCCC	20	1	506.98	12.06	2030	NA
TL072MUB	U	CFP	10	1	506.98	26.16	6220	NA
TL074ACD	D	SOIC	14	50	507	8	3940	4.32
TL074ACDE4	D	SOIC	14	50	507	8	3940	4.32
TL074ACN	N	PDIP	14	25	506	13.97	11230	4.32
TL074ACNE4	N	PDIP	14	25	506	13.97	11230	4.32
TL074BCD	D	SOIC	14	50	507	8	3940	4.32
TL074BCDE4	D	SOIC	14	50	507	8	3940	4.32
TL074BCN	N	PDIP	14	25	506	13.97	11230	4.32
TL074BCNE4	N	PDIP	14	25	506	13.97	11230	4.32
TL074CD	D	SOIC	14	50	507	8	3940	4.32
TL074CDG4	D	SOIC	14	50	507	8	3940	4.32
TL074CN	N	PDIP	14	25	506	13.97	11230	4.32
TL074CN	N	PDIP	14	25	506	13.97	11230	4.32
TL074CNE4	N	PDIP	14	25	506	13.97	11230	4.32
TL074CNE4	N	PDIP	14	25	506	13.97	11230	4.32
TL074CPW	PW	TSSOP	14	90	530	10.2	3600	3.5
TL074ID	D	SOIC	14	50	507	8	3940	4.32
TL074IDE4	D	SOIC	14	50	507	8	3940	4.32
TL074IDG4	D	SOIC	14	50	507	8	3940	4.32
TL074IN	N	PDIP	14	25	506	13.97	11230	4.32
TL074MFK	FK	LCCC	20	1	506.98	12.06	2030	NA
TL074MFKB	FK	LCCC	20	1	506.98	12.06	2030	NA
TL074MWB	W	CFP	14	1	506.98	26.16	6220	NA

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

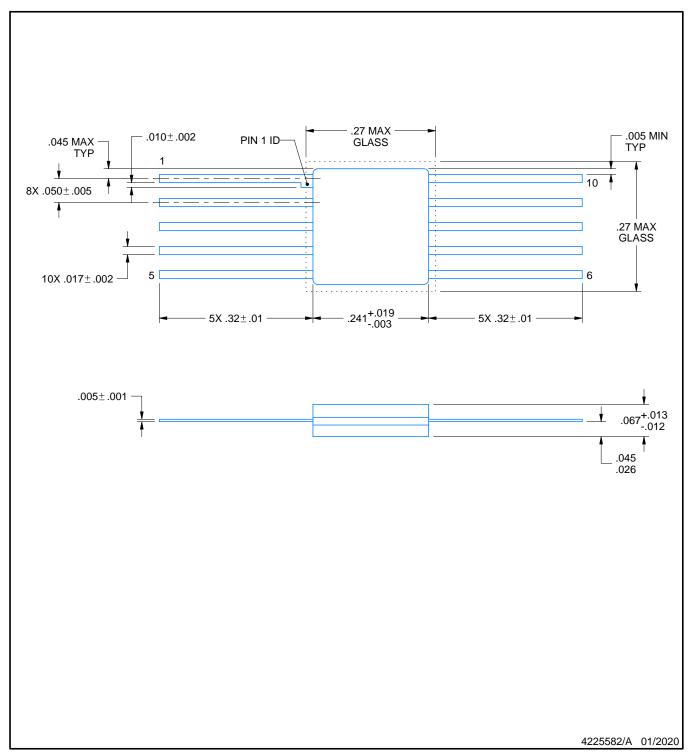
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150



CERAMIC FLATPACK



- 1. All linear dimensions are in inches. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DCK (R-PDSO-G5)

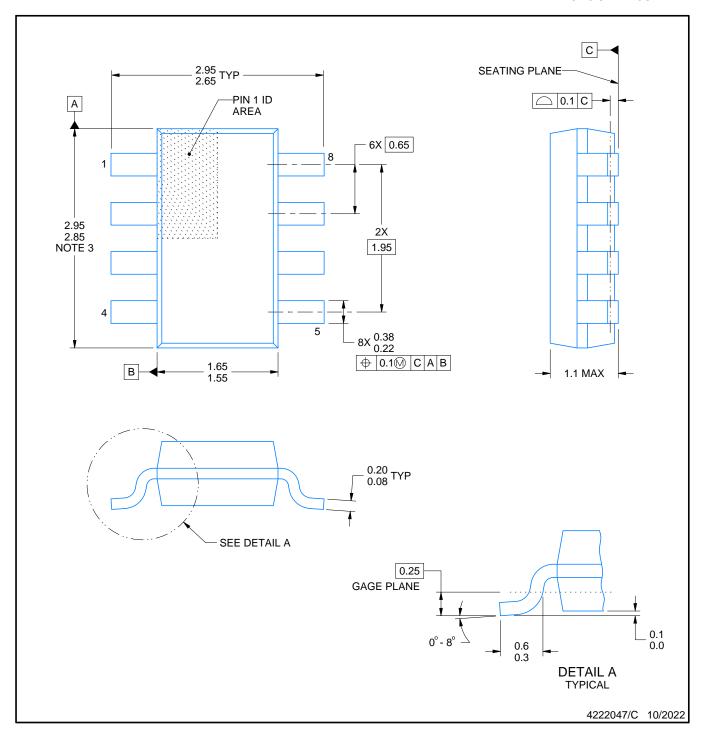
PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





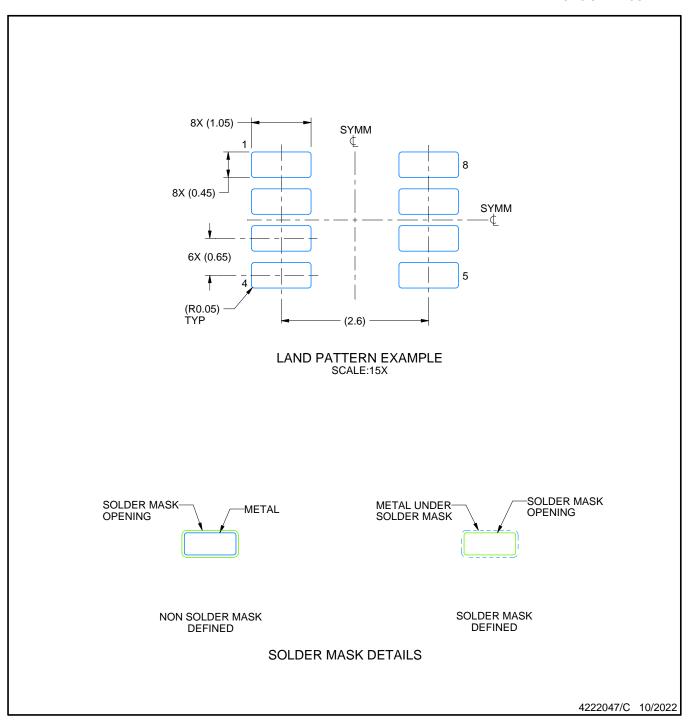


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.

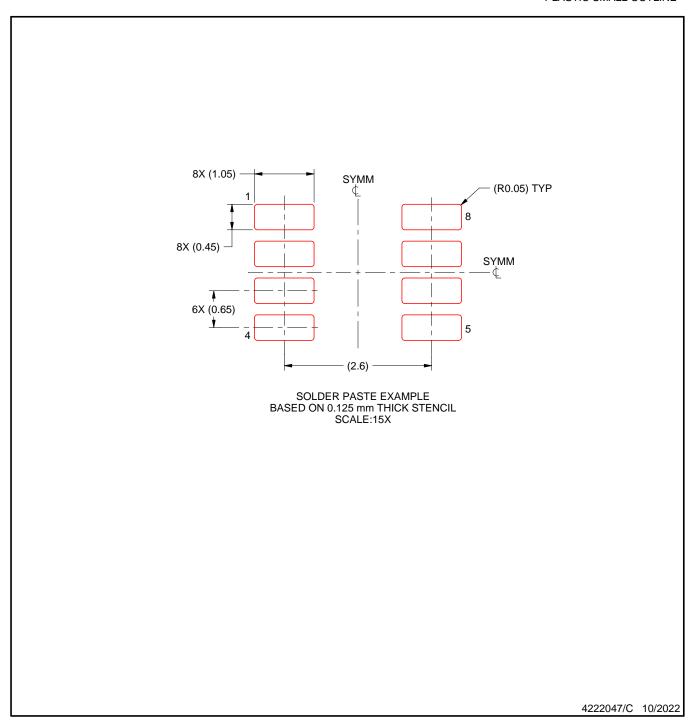




NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

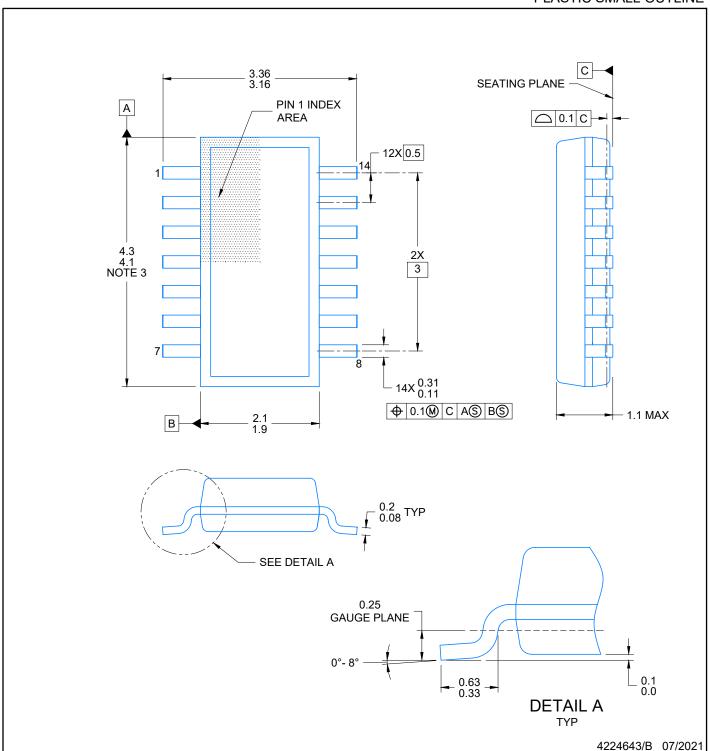




NOTES: (continued)

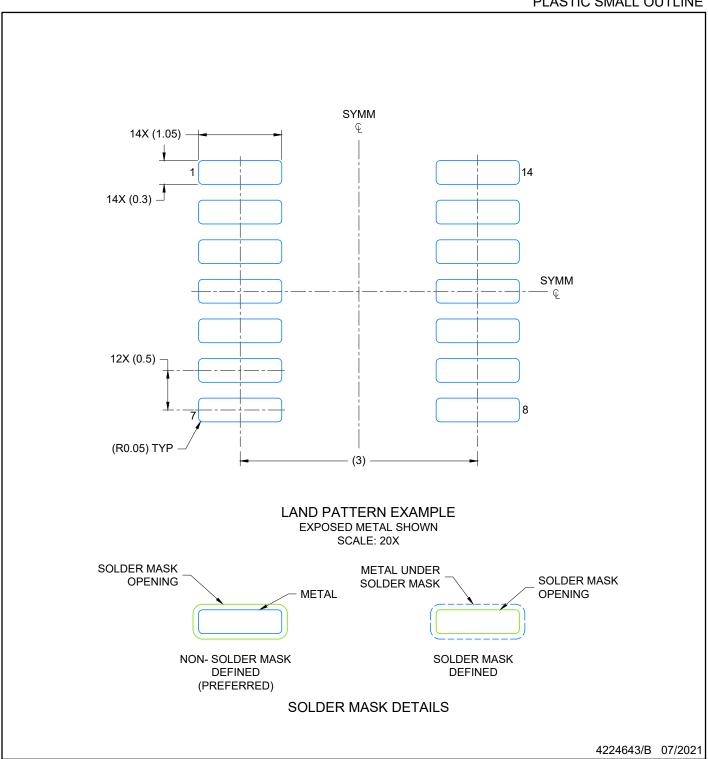
- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.





- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- 5. Reference JEDEC Registration MO-345, Variation AB

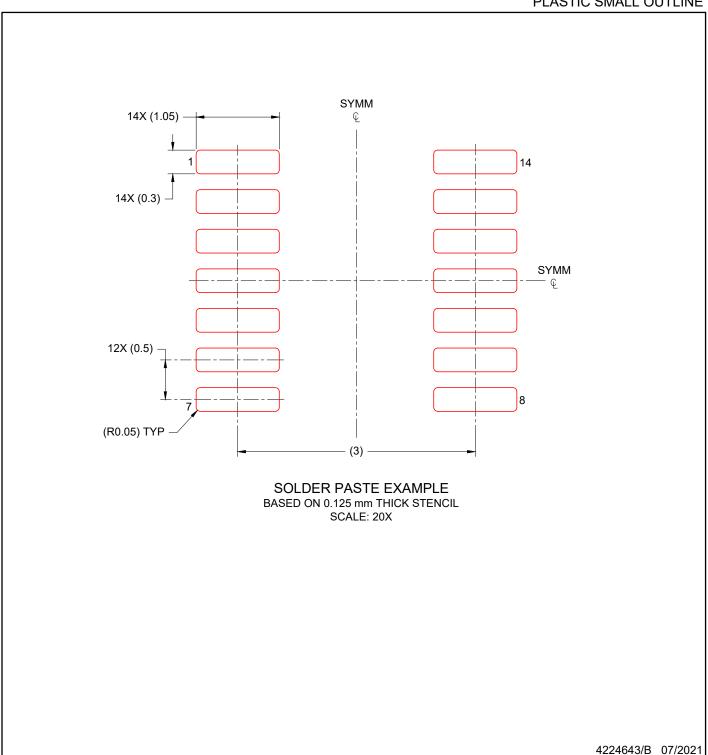




NOTES: (continued)

- Publication IPC-7351 may have alternate designs.
- Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE TRANSISTOR



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

^{8.} Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PS (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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